

28-BIT TO 56-BIT REGISTERED BUFFER WITH ADDRESS-PARITY TEST

FEATURES

- Member of the Texas Instruments Widebus+™ Family
- Pinout Optimizes DDR2 DIMM PCB Layout
- 1-to-2 Outputs Support Stacked DDR2 DIMMs
- One Device Per DIMM Required
- Chip-Select Inputs Gate the Data Outputs from Changing State and Minimizes System Power Consumption
- Output Edge-Control Circuitry Minimizes Switching Noise in an Unterminated Line
- Supports SSTL_18 Data Inputs
- Differential Clock (CLK and $\overline{\text{CLK}}$) Inputs

- Supports LVCMOS Switching Levels on the Chip-Select Gate-Enable, Control, and $\overline{\text{RESET}}$ Inputs
- Checks Parity on DIMM-Independent Data Inputs
- Supports industrial temperature range (-40°C to 85°C)
- $\overline{\text{RESET}}$ Input Disables Differential Input Receivers, Resets All Registers, and Forces All Outputs Low, Except QERR

APPLICATIONS

- Heavily loaded DDR2 registered DIMM

DESCRIPTION

This 28-bit 1:2 configurable registered buffer is designed for 1.7-V to 1.9-V V_{CC} operation. One device per DIMM is required to drive up to 18 stacked SDRAM loads or two devices per DIMM are required to drive up to 36 stacked SDRAM loads.

All inputs are SSTL_18, except the chip-select gate-enable (CSGEN), control (C), and reset ($\overline{\text{RESET}}$) inputs, which are LVCMOS. All outputs are edge-controlled circuits optimized for unterminated DIMM loads, and meet SSTL_18 specifications, except the open-drain error (QERR) output.

The 74SSTUB32868A operates from a differential clock (CLK and $\overline{\text{CLK}}$). Data are registered at the crossing of CLK going high and $\overline{\text{CLK}}$ going low.

The 74SSTUB32868A accepts a parity bit from the memory controller on the parity bit (PAR_IN) input, compares it with the data received on the DIMM-independent D-inputs (D1–D5, D7, D9–D12, D17–D28 when C = 0; or D1–D12, D17–D20, D22, D24–D28 when C = 1) and indicates whether a parity error has occurred on the open-drain QERR pin (active low). The convention is even parity; that is, valid parity is defined as an even number of ones across the DIMM-independent data inputs combined with the parity input bit. To calculate parity, all DIMM-independent D-inputs must be tied to a known logic state.

The 74SSTUB32868A includes a parity checking function. Parity, which arrives one cycle after the data input to which it applies, is checked on the PAR_IN input of the device. Two clock cycles after the data are registered, the corresponding QERR signal is generated.

ORDERING INFORMATION⁽¹⁾

T_A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
-40°C to +85°C	TFBGA-ZRH	Tape and Reel	74SSTUB32868AZRHR	SB868A

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

(2) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus+ is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

DESCRIPTION (CONTINUED)

If an error occurs and the $\overline{QERR}$ output is driven low, it stays latched low for a minimum of two clock cycles or until $\overline{RESET}$ is driven low. If two or more consecutive parity errors occur, the $\overline{QERR}$ output is driven low and latched low for a clock duration equal to the parity error duration or until $\overline{RESET}$ is driven low. If a parity error occurs on the clock cycle before the device enters the low-power mode (LPM) and the $\overline{QERR}$ output is driven low, it stays latched low for the LPM duration plus two clock cycles or until $\overline{RESET}$ is driven low. The DIMM-dependent signals (DCKE0, DCKE1, DODT0, DODT1, $\overline{DCS0}$ and $\overline{DCS1}$) are not included in the parity check computation.

The C input controls the pinout configuration from register-A configuration (when low) to register-B configuration (when high). The C input should not be switched during normal operation. It should be hard-wired to a valid low or high level to configure the register in the desired mode.

In the DDR2 RDIMM application, $\overline{RESET}$ is specified to be completely asynchronous with respect to CLK and $\overline{CLK}$. Therefore, no timing relationship can be ensured between the two. When entering reset, the register is cleared and the data outputs are driven low quickly, relative to the time to disable the differential input receivers. However, when coming out of reset, the register becomes active quickly, relative to the time to enable the differential input receivers. As long as the data inputs are low, and the clock is stable during the time from the low-to-high transition of $\overline{RESET}$ until the input receivers are fully enabled, the design of the 74SSTUB32868A must ensure that the outputs remain low, thus ensuring no glitches on the output.

To ensure defined outputs from the register before a stable clock has been supplied, $\overline{RESET}$ must be held in the low state during power up.

The device supports low-power standby operation. When $\overline{RESET}$ is low, the differential input receivers are disabled, and undriven (floating) data, clock, and reference voltage (V_{REF}) inputs are allowed. In addition, when $\overline{RESET}$ is low, all registers are reset and all outputs are forced low except $\overline{QERR}$. The LVCMOS $\overline{RESET}$ and C inputs always must be held at a valid logic high or low level.

The device also supports low-power active operation by monitoring both system chip select ($\overline{DCS0}$ and $\overline{DCS1}$) and CSGEN inputs and will gate the Qn outputs from changing states when CSGEN, $\overline{DCS0}$, and $\overline{DCS1}$ inputs are high. If CSGEN, $\overline{DCS0}$ or $\overline{DCS1}$ input is low, the Qn outputs function normally. Also, if both $\overline{DCS0}$ and $\overline{DCS1}$ inputs are high, the device will gate the $\overline{QERR}$ output from changing states. If either $\overline{DCS0}$ or $\overline{DCS1}$ is low, the $\overline{QERR}$ output functions normally. The $\overline{RESET}$ input has priority over the $\overline{DCS0}$ and $\overline{DCS1}$ control and when driven low forces the Qn outputs low, and the $\overline{QERR}$ output high. If the chip-select control functionality is not desired, then the CSGEN input can be hard-wired to ground, in which case, the setup-time requirement for $\overline{DCS0}$ and $\overline{DCS1}$ would be the same as for the other D data inputs. To control the low-power mode with $\overline{DCS0}$ and $\overline{DCS1}$ only, then the CSGEN input should be pulled up to V_{CC} through a pullup resistor.

The two V_{REF} pins (A5 and AB5) are connected together internally by approximately 150 Ω . However, it is necessary to connect only one of the two V_{REF} pins to the external V_{REF} power supply. An unused V_{REF} pin should be terminated with a V_{REF} coupling capacitor.

ABSOLUTE MAXIMUM RATINGS

Over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		VALUE	UNIT
V _{CC}	Supply voltage range	–0.5 to 2.5	V
V _I	Input voltage range (see notes ⁽²⁾ and ⁽³⁾)	–0.5 to V _{CC} + 0.5	V
V _O	Output voltage range (see notes ⁽²⁾ and ⁽³⁾)	–0.5 to V _{CC} + 0.5	V
I _{IK}	Input clamp current (V _I < 0, V _I > V _{CC})	±50	mA
I _{OK}	Output clamp current (V _I < 0, V _O > V _{CC})	±50	mA
I _O	Continuous output current (V _O = 0 to V _{CC})	±50	mA
I _{CC}	Continuous current through each V _{CC} or GND	±100	mA
R _{θJA}	Thermal resistance, junction-to-ambient (see note ⁽⁴⁾)	No airflow	46.8
		Airflow 200 ft/min	42.9
R _{θJC}	Thermal resistance, junction-to-case (see note ⁽⁴⁾)	No airflow	17.9
T _{stg}	Storage temperature range	–65 to +150	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (3) This value is limited to 2.5 V maximum.
- (4) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

Over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	NOM	MAX	UNIT
SUPPLY VOLTAGES, CURRENTS AND TEMPERATURE RANGE					
V _{CC}	Supply voltage	1.7		1.9	V
V _{REF}	Reference voltage	0.49 × V _{CC}	0.5 × V _{CC}	0.51 × V _{CC}	V
V _{TT}	Termination voltage	V _{REF} – 40 mV	V _{REF}	V _{REF} + 40 mV	V
V _I	Input voltage	0		V _{CC}	V
V _{IH}	AC high-level input voltage	Data inputs, $\overline{\text{DCSn}}$, PAR_IN		V _{REF} + 250 mV	V
V _{IL}	AC low-level input voltage	Data inputs, $\overline{\text{DCSn}}$, PAR_IN		V _{REF} – 250 mV	V
V _{IH}	DC high-level input voltage	Data inputs, $\overline{\text{DCSn}}$, PAR_IN		V _{REF} + 125 mV	V
V _{IL}	DC low-level input voltage	Data inputs, $\overline{\text{DCSn}}$, PAR_IN		V _{REF} – 125 mV	V
V _{IH}	High-level input voltage	$\overline{\text{RESET}}$, CSGEN, C	0.65 × V _{CC}		V
V _{IL}	Low-level input voltage	$\overline{\text{RESET}}$, CSGEN, C		0.35 × V _{CC}	V
V _{ICR}	Common-mode input voltage range	CLK, $\overline{\text{CLK}}$	0.675	1.125	V
V _{I(PP)}	Peak-to-peak input voltage	CLK, $\overline{\text{CLK}}$	0.6		V
I _{OH}	High-level output current	Q outputs		–12	mA
I _{OL}	Low-level output current	Q outputs		12	mA
		$\overline{\text{QERR}}$ output	30		
T _A	Operating free-air temperature	–40		85	°C

- (1) The $\overline{\text{RESET}}$ and Cn inputs of the device must be held at valid logic voltage levels (not floating) to ensure proper device operation. The differential inputs must not be floating unless $\overline{\text{RESET}}$ is low. See the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number [SCBA004](#) (available for download at [www.ti.com](#)).

ELECTRICAL CHARACTERISTICS

over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITION		V _{CC}	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OH}	Q outputs	I _{OH} = –100 µA		1.7 V to 1.9 V	V _{CC} – 0.2			V
		I _{OH} = –8 mA		1.7 V	1.2			
V _{OL}	Q outputs	I _{OL} = 100 µA		1.7 V to 1.9 V			0.2	V
		I _{OL} = 8 mA		1.7 V			0.5	
	$\overline{\text{QERR}}$	I _{OL} = 25 mA		1.7 V			0.5	
I _I	PAR_IN	V _I = GND		1.9 V			–5	µA
		V _I = V _{CC}					25	
	All other inputs ⁽²⁾	V _I = V _{CC} or GND					±5	
I _{OZ}	$\overline{\text{QERR}}$ outputs	V _O = V _{CC} or GND		1.9 V			±10	µA
I _{CC}	Static standby ⁽³⁾	$\overline{\text{RESET}}$ = GND	I _O = 0	1.9 V			200 ⁽³⁾	µA
	Static operating	$\overline{\text{RESET}}$ = V _{CC} , V _I = V _{IH(AC)} or V _{IL(AC)}					80	mA
I _{CC(D)}	Dynamic operating – clock only	$\overline{\text{RESET}}$ = V _{CC} , V _I = V _{IH(AC)} or V _{IL(AC)} , CLK and CLK switching 50% duty cycle	I _O = 0	1.8 V		64		µA/MHz
	Dynamic operating – per each data input	$\overline{\text{RESET}}$ = V _{CC} , V _I = V _{IH(AC)} or V _{IL(AC)} , CLK and CLK switching 50% duty cycle, One data input switching at one half clock frequency, 50% duty cycle				37		µA/clock MHz/ D inputs
I _{CC(DLP)}	Chip-select-enabled low-power active mode – clock only	$\overline{\text{RESET}}$ = V _{CC} , V _I = V _{IH(AC)} or V _{IL(AC)} , CLK and CLK switching 50% duty cycle	I _O = 0	1.8 V		68		µA/MHz
	Chip-select-enabled low-power active mode	$\overline{\text{RESET}}$ = V _{CC} , V _I = V _{IH(AC)} or V _{IL(AC)} , CLK and CLK switching 50% duty cycle, One data input switching at one half clock frequency, 50% duty cycle				2.7		µA/clock MHz/ D inputs
C _I	Data inputs, DCSn, PAR_IN, CSGEN	V _I = V _{REF} ±250 mV		1.8 V	2	2.5	3	pF
	CLK, $\overline{\text{CLK}}$	V _{ICR} = 0.9 V, V _{I(PP)} = 600 mV			2		3	
	$\overline{\text{RESET}}$	V _I = V _{CC} or GND				4		

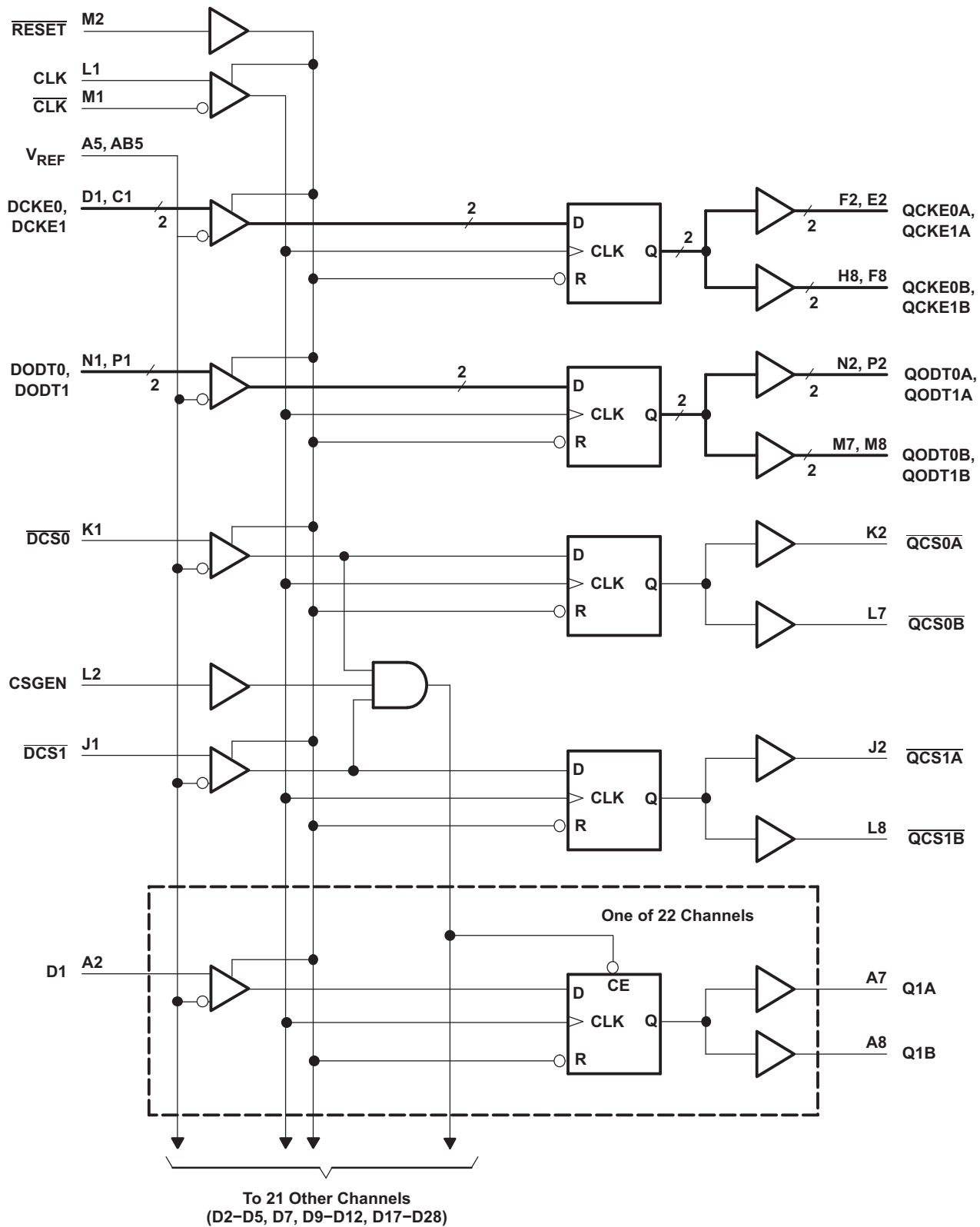
(1) All typical values are at V_{CC} = 1.8 V, T_A = +25°C.

(2) Each V_{REF} pin (A5 or AB5) should be tested independently, with the other (untested) pin open.

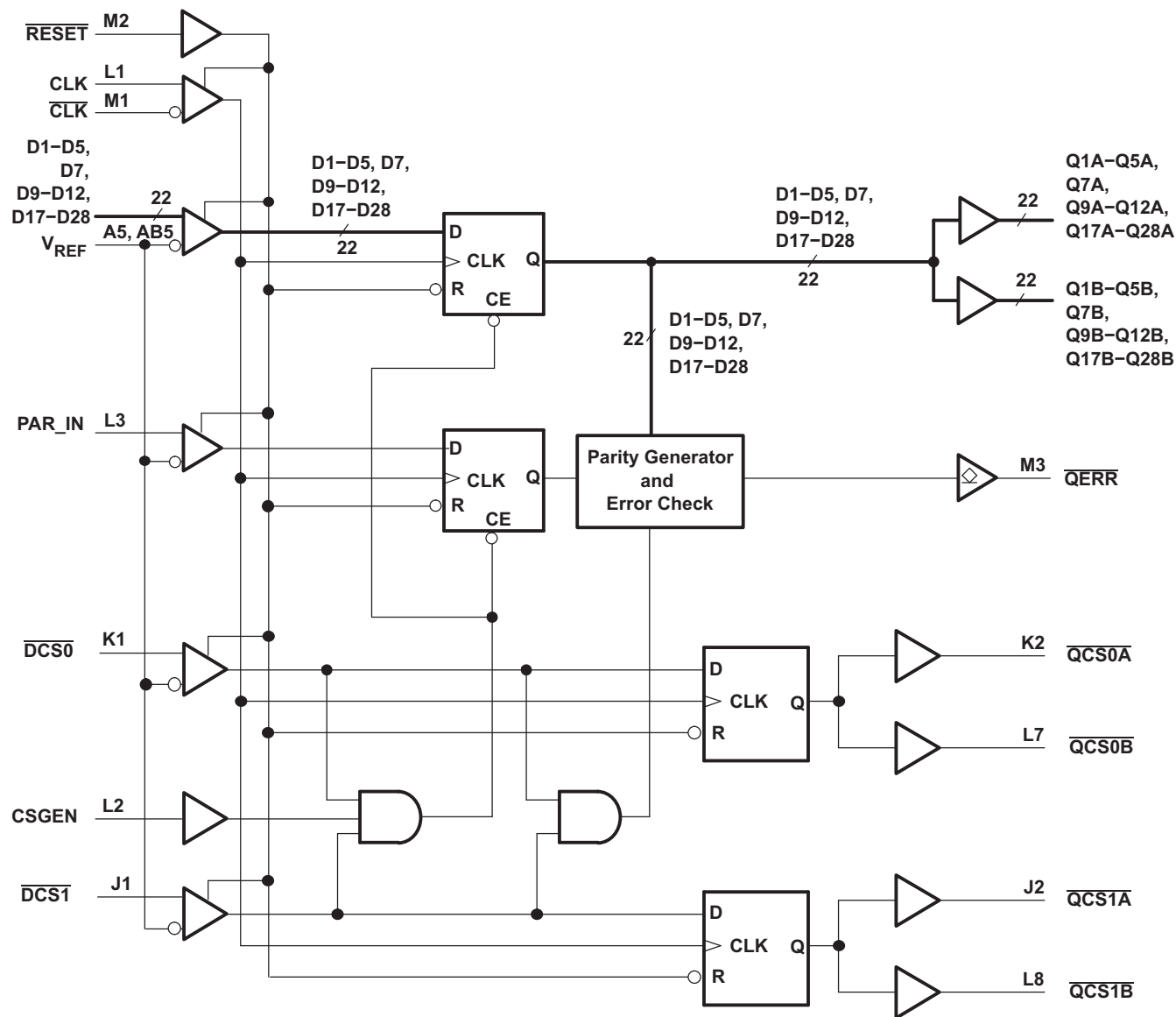
(3) The maximum static standby current I_{CC} is 100µA if the device is exposed to commercial temperature range (0°C to 70°C) only. For industrial temperature range (–40°C to 85°C) static I_{CC} is 200µA.

PACKAGE (TOP VIEW)									Terminal Assignment for Register-A (C = 0)								
1 2 3 4 5 6 7 8									1 2 3 4 5 6 7 8								
A	○	○	○	○	○	○	○	○	A	D2	D1	C	GND	V _{REF}	GND	Q1A	Q1B
B	○	○	○	○	○	○	○	○	B	D4	D3	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q2A	Q2B
C	○	○	○	○	○	○	○	○	C	D6 (DCKE1)	D5	GND	GND	GND	GND	Q3A	Q3B
D	○	○	○	○	○	○	○	○	D	D8 (DCKE0)	D7	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q4A	Q4B
E	○	○	○	○	○	○	○	○	E	D9	Q6A (QCKE1A)	GND	GND	GND	GND	Q5A	Q5B
F	○	○	○	○	○	○	○	○	F	D10	Q8A (QCKE0A)	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q7A	Q6B (QCKE1B)
G	○	○	○	○	○	○	○	○	G	D11	Q10A	GND	GND	GND	GND	Q9A	Q7B
H	○	○	○	○	○	○	○	○	H	D12	Q12A	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q11A	Q8B (QCKE0B)
J	○	○	○	○	○	○	○	○	J	D13 (DCS1)	Q13A (QCS1A)	GND	GND	GND	GND	Q10B	Q9B
K	○	○	○	○	○	○	○	○	K	D14 (DCS0)	Q14A (QCS0A)	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q12B	Q11B
L	○	○	○	○	○	○	○	○	L	CLK	CSGEN	PAR_IN	GND	GND	GND	Q14B (QCS0B)	Q13B (QCS1B)
M	○	○	○	○	○	○	○	○	M	CLK	RESET	QERR	V _{CC}	V _{CC}	V _{CC}	Q15B (QODT0B)	Q16B (QODT1B)
N	○	○	○	○	○	○	○	○	N	D15 (DODT0)	Q15A (QODT0A)	GND	GND	GND	GND	Q17B	Q18B
P	○	○	○	○	○	○	○	○	P	D16 (DODT1)	Q16A (QODT1A)	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q19B	Q20B
R	○	○	○	○	○	○	○	○	R	D17	Q17A	GND	GND	GND	GND	Q18A	Q21B
T	○	○	○	○	○	○	○	○	T	D18	Q19A	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q20A	Q22B
U	○	○	○	○	○	○	○	○	U	D19	Q21A	GND	GND	GND	GND	Q22A	Q23B
V	○	○	○	○	○	○	○	○	V	D20	Q23A	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q24A	Q24B
W	○	○	○	○	○	○	○	○	W	D21	D22	GND	GND	GND	GND	Q25A	Q25B
Y	○	○	○	○	○	○	○	○	Y	D23	D24	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q26A	Q26B
AA	○	○	○	○	○	○	○	○	AA	D25	D26	GND	GND	GND	GND	Q27A	Q27B
AB	○	○	○	○	○	○	○	○	AB	D27	D28	NC	V _{CC}	V _{REF}	V _{CC}	Q28A	Q28B

- A. Each pin name in parentheses indicates the DDR2 DIMM signal name.
 B. NC - No internal connection.

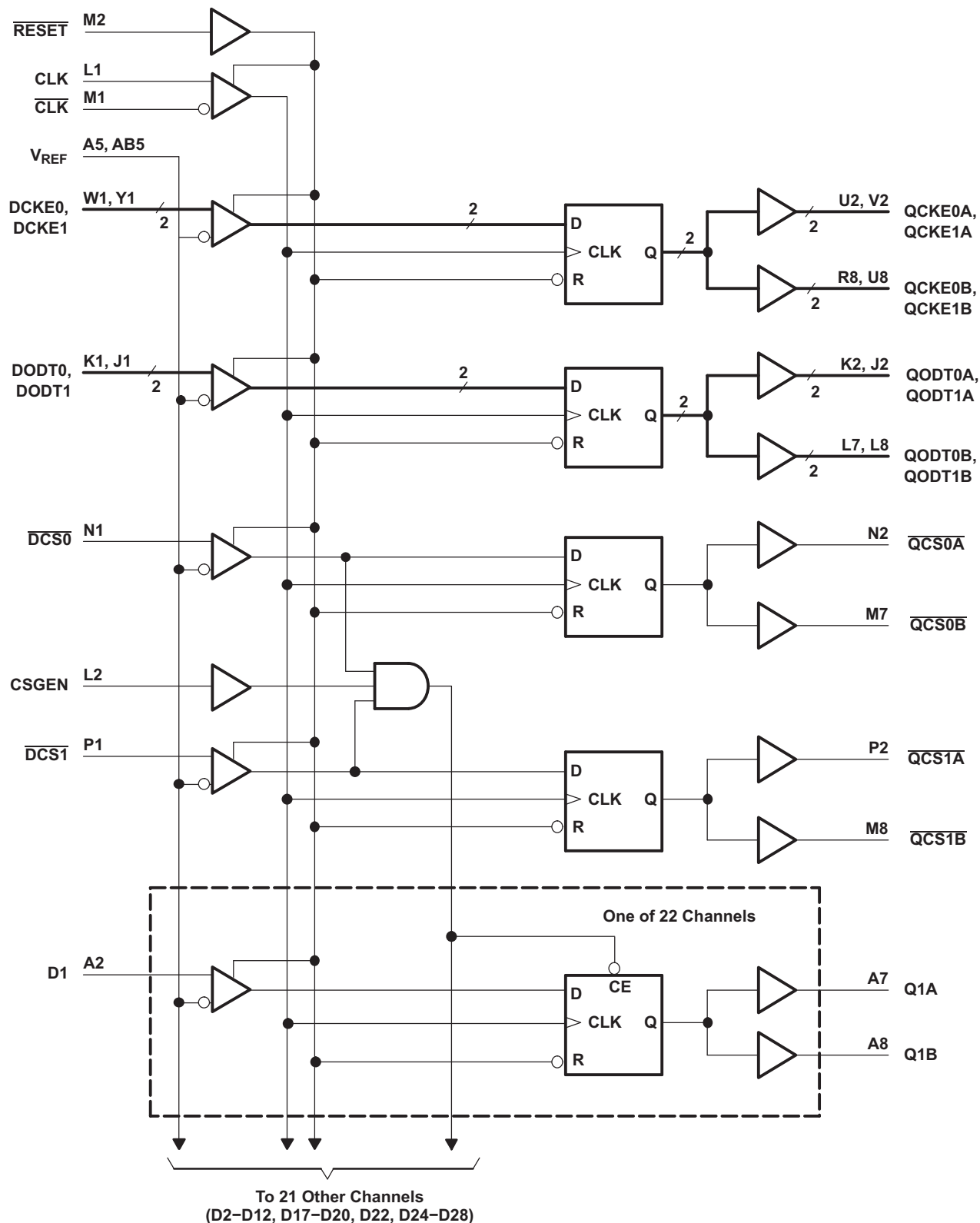
Logic Diagram for Register-A Configuration (Positive Logic); C = 0

Parity Logic Diagram for Register-A Configuration (Positive Logic); C = 0

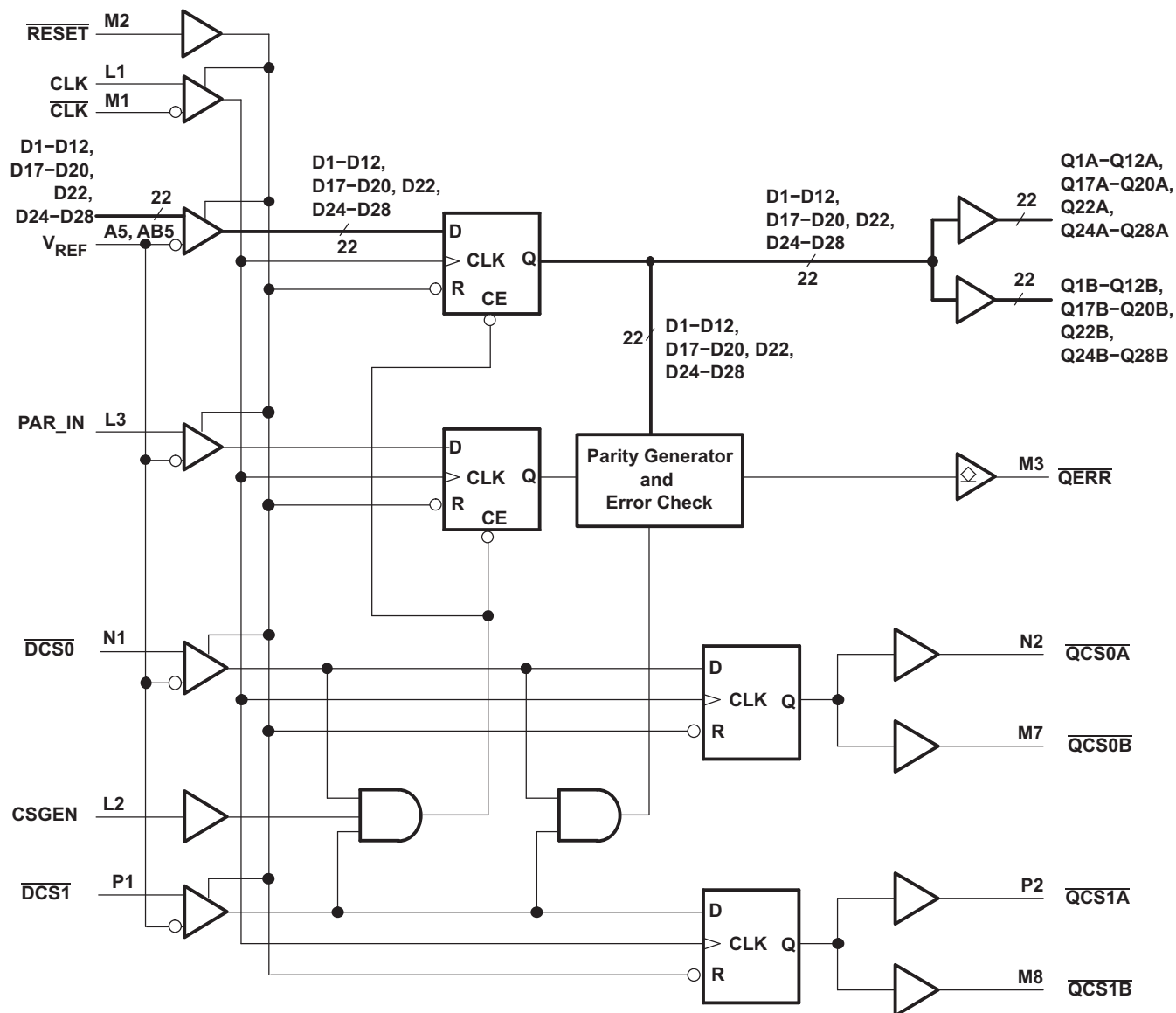


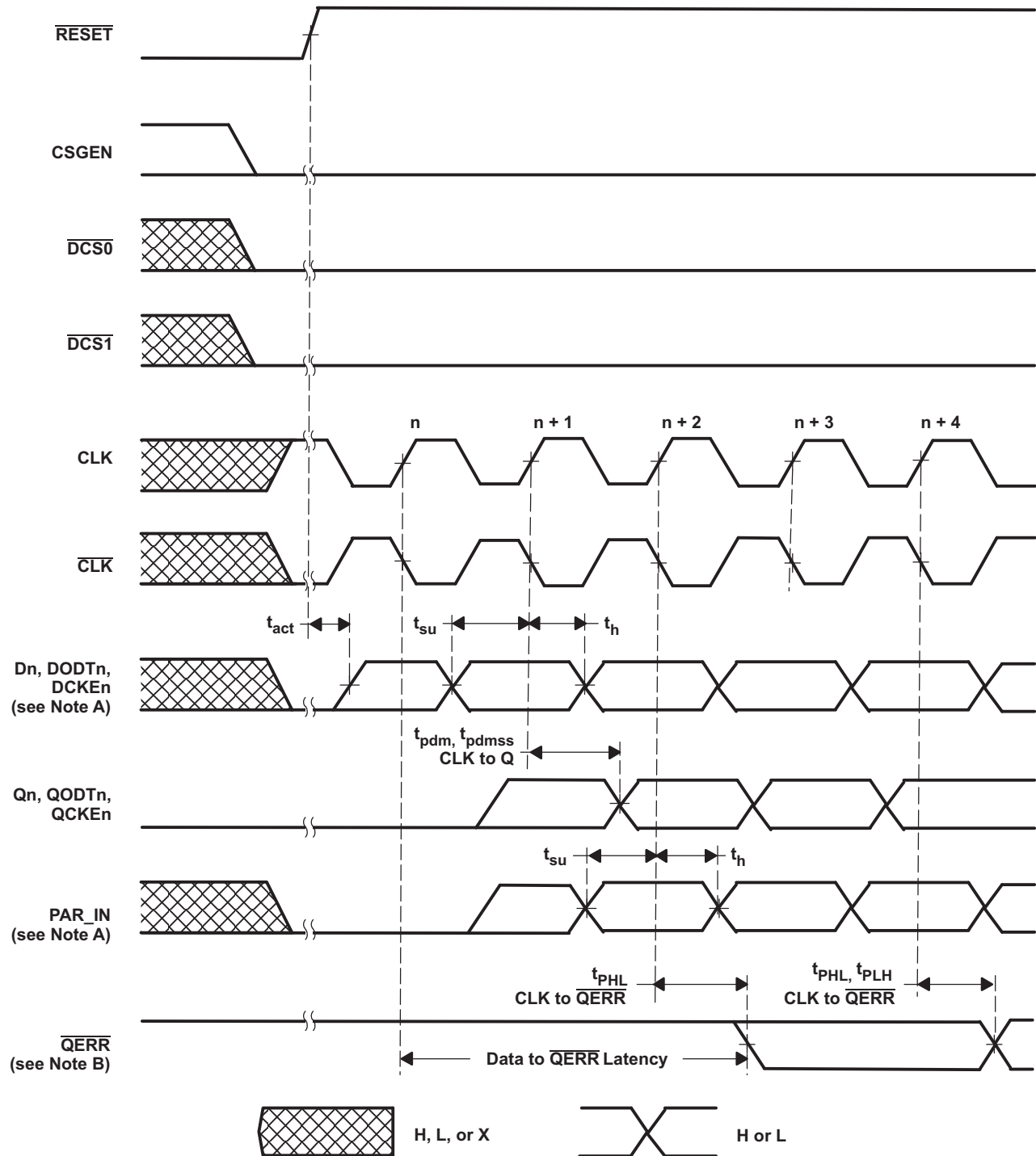
PACKAGE (TOP VIEW)								Terminal Assignment for Register-B (C = 1)									
	1	2	3	4	5	6	7	8		1	2	3	4	5	6	7	8
A	○	○	○	○	○	○	○	○	A	D2	D1	C	GND	V _{REF}	GND	Q1A	Q1B
B	○	○	○	○	○	○	○	○	B	D4	D3	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q2A	Q2B
C	○	○	○	○	○	○	○	○	C	D6	D5	GND	GND	GND	GND	Q3A	Q3B
D	○	○	○	○	○	○	○	○	D	D8	D7	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q4A	Q4B
E	○	○	○	○	○	○	○	○	E	D9	Q6A	GND	GND	GND	GND	Q5A	Q5B
F	○	○	○	○	○	○	○	○	F	D10	Q8A	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q7A	Q6B
G	○	○	○	○	○	○	○	○	G	D11	Q10A	GND	GND	GND	GND	Q9A	Q7B
H	○	○	○	○	○	○	○	○	H	D12	Q12A	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q11A	Q8B
J	○	○	○	○	○	○	○	○	J	D13 (DODT1)	Q13A (DODT1A)	GND	GND	GND	GND	Q10B	Q9B
K	○	○	○	○	○	○	○	○	K	D14 (DODT0)	Q14A (QODT0A)	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q12B	Q11B
L	○	○	○	○	○	○	○	○	L	CLK	CSGEN	PAR_IN	GND	GND	GND	Q14B (QODT0B)	Q13B (QODT1B)
M	○	○	○	○	○	○	○	○	M	CLK	RESET	QERR	V _{CC}	V _{CC}	V _{CC}	Q15B (QCS0B)	Q16B (QCS1B)
N	○	○	○	○	○	○	○	○	N	D15 (DCS0)	Q15A (QCS0A)	GND	GND	GND	GND	Q17B	Q18B
P	○	○	○	○	○	○	○	○	P	D16 (DCS1)	Q16A (QCS1A)	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q19B	Q20B
R	○	○	○	○	○	○	○	○	R	D17	Q17A	GND	GND	GND	GND	Q18A	Q21B (QCKE0B)
T	○	○	○	○	○	○	○	○	T	D18	Q19A	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q20A	Q22B
U	○	○	○	○	○	○	○	○	U	D19	Q21A (QCKE0A)	GND	GND	GND	GND	Q22A	Q23B (QCKE1B)
V	○	○	○	○	○	○	○	○	V	D20	Q23A (QCKE1A)	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q24A	Q24B
W	○	○	○	○	○	○	○	○	W	D21 (DCKE0)	D22	GND	GND	GND	GND	Q25A	Q25B
Y	○	○	○	○	○	○	○	○	Y	D23 (DCKE1)	D24	V _{CC}	V _{CC}	V _{CC}	V _{CC}	Q26A	Q26B
AA	○	○	○	○	○	○	○	○	AA	D25	D26	GND	GND	GND	GND	Q27A	Q27B
AB	○	○	○	○	○	○	○	○	AB	D27	D28	NC	V _{CC}	V _{REF}	V _{CC}	Q28A	Q28B

Logic Diagram for Register-B Configuration (Positive Logic); C = 1

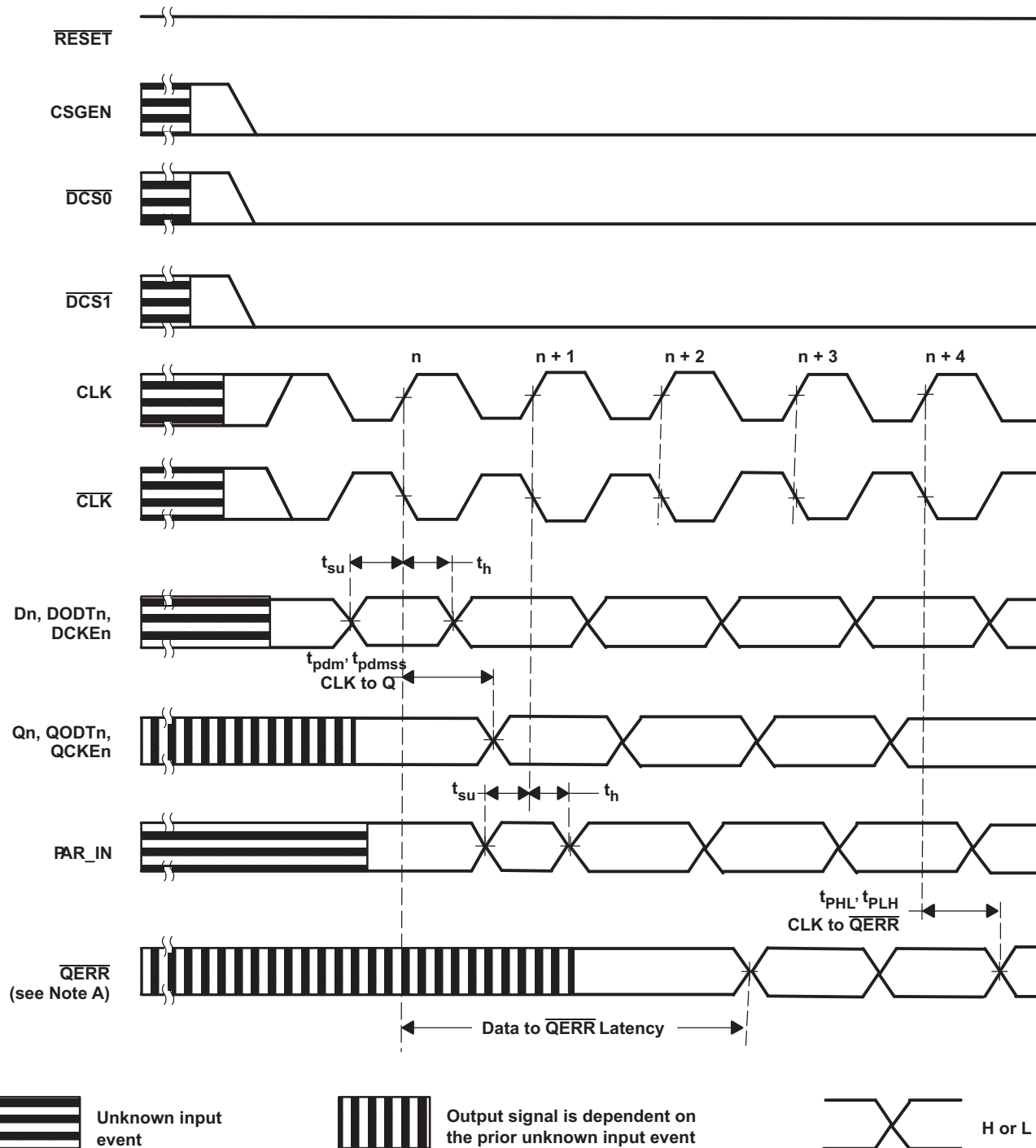


Parity Logic Diagram for Register-B Configuration (Positive Logic); C = 1



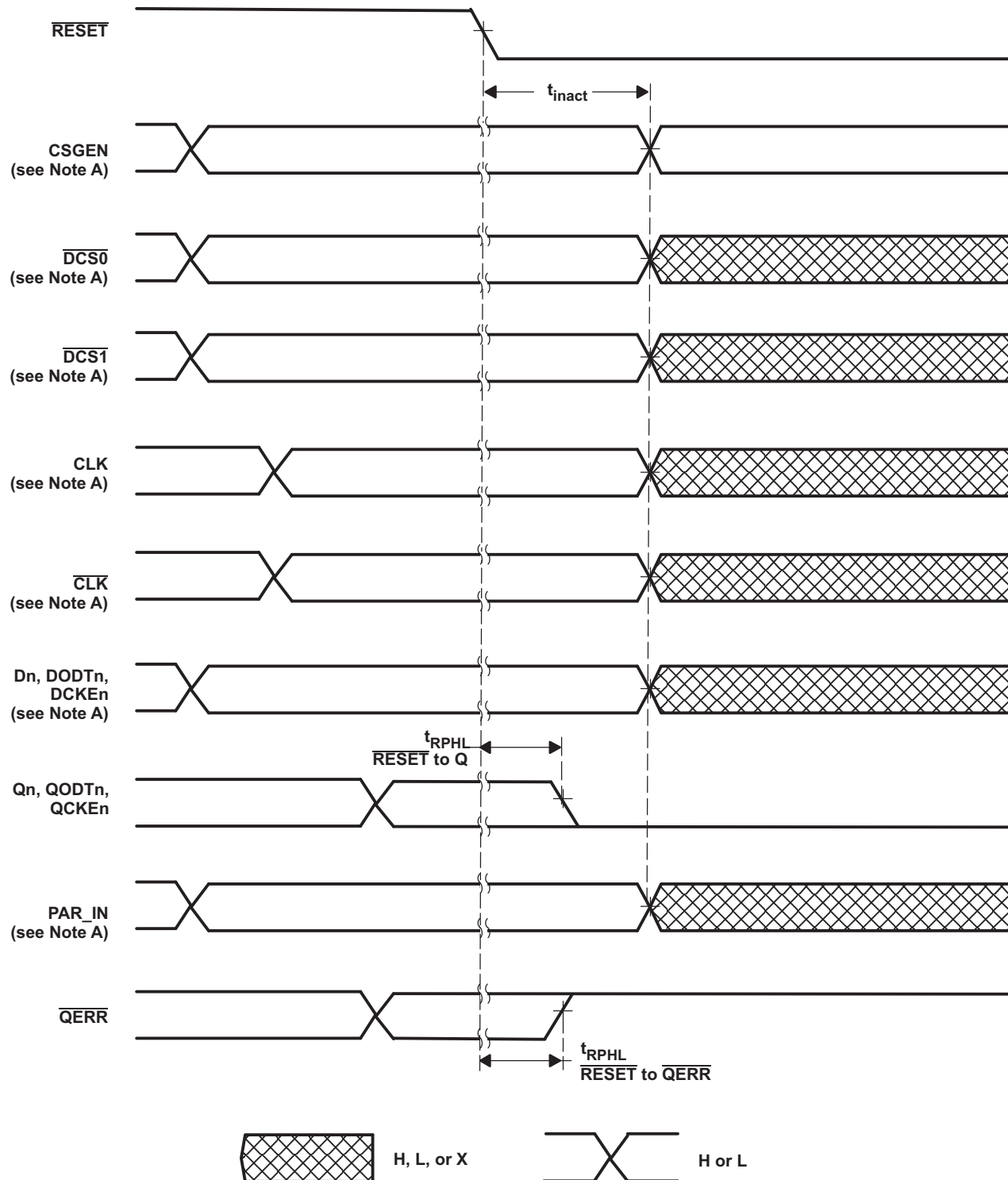
Timing Diagram for 74SSTUB32868A During Start-Up ($\overline{\text{RESET}}$ Switches From L to H)


- After $\overline{\text{RESET}}$ is switched from low to high, all data and PAR_IN input signals must be set and held low for a minimum time of t_{act} max, to avoid a false error.
- If the data is clocked in on the n -clock pulse, the $\overline{\text{QERR}}$ output signal is generated on the $n + 2$ clock pulse, and it is valid on the $n + 3$ clock pulse.

Timing Diagram for 74SSTUB32868A During Normal Operation ($\overline{\text{RESET}} = \text{H}$)

- A. If the data is clocked in on the n -clock pulse, the $\overline{\text{QERR}}$ output signal is generated on the $n + 2$ clock pulse, and it is valid on the $n + 3$ clock pulse. If an error occurs and the $\overline{\text{QERR}}$ output is driven low, it stays latched low for a minimum of two clock cycles or until $\overline{\text{RESET}}$ is driven low.

Timing Diagram for 74SSTUB32868A During Shut-Down ($\overline{\text{RESET}}$ Switches From H to L)



- A. After $\overline{\text{RESET}}$ is switched from high to low, all data and clock input signals must be held at logic levels (not floating) for a minimum time of t_{inact} max, to avoid a false error.

TERMINAL FUNCTIONS

TERMINAL NAME	DESCRIPTION	ELECTRICAL CHARACTERISTICS
GND	Ground	Ground input
V _{CC}	Power supply voltage	1.8 V nominal
V _{REF}	Input reference voltage	0.9 V nominal
CLK	Positive master clock input	Differential input
$\overline{\text{CLK}}$	Negative master clock input	Differential input
C	Configuration control input - Register A or Register B	LVC MOS input
$\overline{\text{RESET}}$	Asynchronous reset input – resets registers and disables V _{REF} , data and clock differential-input receivers. When RESET is low, all the Q outputs are forced low and the QERR output is forced high.	LVC MOS input
CSGEN	Chip select gate enable. When high, D1–D28 ⁽¹⁾ inputs are latched only when at least one chip select input is low during the rising edge of the clock. When low, the D1–D28 ⁽¹⁾ inputs are latched and redriven on every rising edge of the clock.	LVC MOS input
D1–D28	Data input. Data are clocked in on the crossing of the rising edge of CLK and the falling edge of CLK	SSTL_18 input
$\overline{\text{DCS0}}$, $\overline{\text{DCS1}}$	Chip select inputs. These pins initiate DRAM address/command decodes, and as such at least one will be low when a valid address/command is present. The Register can be programmed to redrive all D inputs (CSGEN high) only when at least one chip select input is low. If CSGEN, $\overline{\text{DCS0}}$, and $\overline{\text{DCS1}}$ inputs are high, D1–D28 ⁽²⁾ inputs will be disabled.	SSTL_18 input
DODT0, DODT1	The outputs of this register bit will not be suspended by the $\overline{\text{DCS0}}$ and $\overline{\text{DCS1}}$ control.	SSTL_18 input
DCKE0, DCKE1	The outputs of this register bit will not be suspended by the $\overline{\text{DCS0}}$ and $\overline{\text{DCS1}}$ control.	SSTL_18 input
PAR_IN	Parity input. The parity input arrives one clock cycle after the corresponding data input. Pulldown resistor of typical 150kΩ to GND.	SSTL_18 input with pulldown
Q1–Q28 ⁽³⁾	Data outputs that are suspended by the $\overline{\text{DCS0}}$ and $\overline{\text{DCS1}}$ control.	1.8 V CMOS output
$\overline{\text{QCS0}}$, $\overline{\text{QCS1}}$	Data output that will not be suspended by the $\overline{\text{DCS0}}$ and $\overline{\text{DCS1}}$ control.	1.8 V CMOS output
QODT0, QODT1	Data output that will not be suspended by the $\overline{\text{DCS0}}$ and $\overline{\text{DCS1}}$ control.	1.8 V CMOS output
QCKE0, QCKE1	Data output that will not be suspended by the $\overline{\text{DCS0}}$ and $\overline{\text{DCS1}}$ control.	1.8 V CMOS output
$\overline{\text{QERR}}$	Output error bit. This bit is generated two clock cycles after the corresponding data is registered.	Open-drain output
NC	No internal connection	

- (1) Data inputs = D1–D5, D7, D9–D12, D17–D28 when C = 0.
Data inputs = D1–D12, D17–D20, D22, D24–D28 when C = 1.
- (2) Data inputs = D1–D5, D7, D9–D12, D17–D28 when C = 0.
Data inputs = D1–D12, D17–D20, D22, D24–D28 when C = 1.
- (3) Data outputs = Q1–Q5, Q7, Q9–Q12, Q17–Q28 when C = 0.
Data outputs = Q1–Q12, Q17–Q20, Q22, Q24–Q28 when C = 1.

FUNCTION TABLE

INPUTS							OUTPUTS			
$\overline{\text{RESET}}$	$\overline{\text{DCS0}}$	$\overline{\text{DCS1}}$	CSGEN	CLK	$\overline{\text{CLK}}$	dn, DODTn, DCKEn	Qn	$\overline{\text{QCS0}}$	$\overline{\text{QCS1}}$	QODT, QCKE
H	L	L	X	↑	↓	L	L	L	L	L
H	L	L	X	↑	↓	H	H	L	L	H
H	L	L	X	L or H	L or H	X	Q ₀	Q ₀	Q ₀	Q ₀
H	L	H	X	↑	↓	L	L	L	H	L
H	L	H	X	↑	↓	H	H	L	H	H
H	L	H	X	L or H	L or H	X	Q ₀	Q ₀	Q ₀	Q ₀
H	H	L	X	↑	↓	L	L	H	L	L
H	H	L	X	↑	↓	H	H	H	L	H
H	H	L	X	L or H	L or H	X	Q ₀	Q ₀	Q ₀	Q ₀
H	H	H	L	↑	↓	L	L	H	H	L
H	H	H	L	↑	↓	H	H	H	H	H
H	H	H	L	L or H	L or H	X	Q ₀	Q ₀	Q ₀	Q ₀
H	H	H	H	↑	↓	L	Q ₀	H	H	L
H	H	H	H	↑	↓	H	Q ₀	H	H	H
H	H	H	H	L or H	L or H	X	Q ₀	Q ₀	Q ₀	Q ₀
L	X or floating	X or floating	X or floating	X or floating	X or floating	L	L	L	L	L

PARITY AND STANDBY FUNCTION

INPUTS							OUTPUTS
$\overline{\text{RESET}}$	CLK	$\overline{\text{CLK}}$	$\overline{\text{DCS0}}$	$\overline{\text{DCS1}}$	Σ OF INPUTS = H D1 - D22	PAR_IN ⁽¹⁾	$\overline{\text{QERR}}$ ⁽²⁾
H	↑	↓	L	X	Even	L	H
H	↑	↓	L	X	Odd	L	L
H	↑	↓	L	X	Even	H	L
H	↑	↓	L	X	Odd	H	H
H	↑	↓	X	L	Even	L	H
H	↑	↓	X	L	Odd	L	L
H	↑	↓	X	L	Even	H	L
H	↑	↓	X	L	Odd	H	H
H	↑	↓	H	H	X	X	$\overline{\text{QERR}}_0$ ⁽³⁾
H	L or H	L or H	X	X	X	X	$\overline{\text{QERR}}_0$
L	X or floating	X or floating	X or floating	X or floating	X	X or floating	H

- (1) PAR_IN arrives one clock cycle after the data to which it applies.
- (2) This transition assumes that $\overline{\text{QERR}}$ is high at the crossing of CLK going high and $\overline{\text{CLK}}$ going low. If $\overline{\text{QERR}}$ goes low, it stays latched low for a minimum of two clock cycles or until $\overline{\text{RESET}}$ is driven low. If two or more consecutive errors occur, the $\overline{\text{QERR}}$ output is driven low and latched low for a clock duration equal to the parity error duration or until $\overline{\text{RESET}}$ is driven low. For $\overline{\text{QERR}}$ computation, CSGEN is a *do not care*.
- (3) If $\overline{\text{DCS0}}$, $\overline{\text{DCS1}}$ and CSGEN are driven high, the device is placed in a low-power mode (LPM). If a parity error occurs on the clock cycle before the device enters the LPM and the $\overline{\text{QERR}}$ output is driven low, it stays latched low for the LPM duration plus two clock cycles or until $\overline{\text{RESET}}$ is driven low.

TIMING REQUIREMENTS

Over recommended ranges of supply voltage, load, and operating free-air temperature (see [Figure 1](#) and Note ⁽¹⁾)

		V _{CC} = 1.8 V ±0.1 V		
		MIN	MAX	UNIT
f _(clock)	Clock frequency		410	MHz
t _w	Pulse duration, CLK, CLK high or low	1		ns
t _{act}	Differential inputs active time (see Note ⁽²⁾)		10	ns
t _{inact}	Differential inputs inactive time (see Note ⁽³⁾)		15	ns
t _{su}	Setup time	DCSn before CLK↑, CLK↓, CSGEN high	600	ps
		DCSn before CLK↑, CLK↓, CSGEN low	500	
		DODTn, DCKEn, and Data before CLK↑, CLK↓	500	
		PAR_IN before CLK↑, CLK↓	500	
t _h	Hold time	DCSn, DODTn, DCKEn, and Data after CLK↑, CLK↓	400	ps
		PAR_IN after CLK↑, CLK↓	400	

(1) All inputs slew rate is 1 V/ns $\pm 20\%$

(2) V_{REF} must be held at a valid input level and data inputs must be held low for a minimum time of t_{act} max, after $\overline{\text{RESET}}$ is taken high.

(3) V_{REF} , data, and clock inputs must be held at valid voltage levels (not floating) for a minimum time of t_{inact} max, after $\overline{\text{RESET}}$ is taken low.

SWITCHING CHARACTERISTICS

Over recommended ranges of supply voltage, load, and operating free-air temperature (unless otherwise noted)

			$V_{CC} = 1.8\text{ V} \pm 0.1\text{ V}$		
PARAMETER	FROM (INPUT)	TO (OUTPUT)	MIN	MAX	UNIT
f_{max} (see Figure 2)			410		MHz
t_{pdm} ⁽¹⁾ (production test, see Figure 1)	CLK and $\overline{\text{CLK}}$	Q	0.5	1.0	ns
t_{PLH} (see Figure 4)	CLK and $\overline{\text{CLK}}$	$\overline{\text{QERR}}$	1.2	3	ns
t_{PHL} (see Figure 4)			1	2.4	ns
t_{RPHL} ⁽²⁾ (see Figure 2)	$\overline{\text{RESET}}$	Q		3	ns
t_{RPLH} (see Figure 4)	$\overline{\text{RESET}}$	$\overline{\text{QERR}}$		3	ns

(1) The typical difference between min and max does not exceed 400 ps.

(2) Includes 350-ps test-load transmission line delay.

OUTPUT SLEW RATES

over operating free-air temperature range (unless otherwise noted) (see [Figure 3](#))

			$V_{CC} = 1.8\text{ V} \pm 0.1\text{ V}$		
PARAMETER	FROM	TO (OUTPUT)	MIN	MAX	UNIT
dV/dt_r	20%	80%	1	5	V/ns
dV/dt_f	80%	20%	1	5	V/ns
dV/dt_{Δ} ⁽¹⁾	20% to 80%	20% to 80%		1	V/ns

(1) The difference between dV/dt_r (rising edge rate) and dV/dt_f (falling edge).

PARAMETER MEASUREMENT INFORMATION

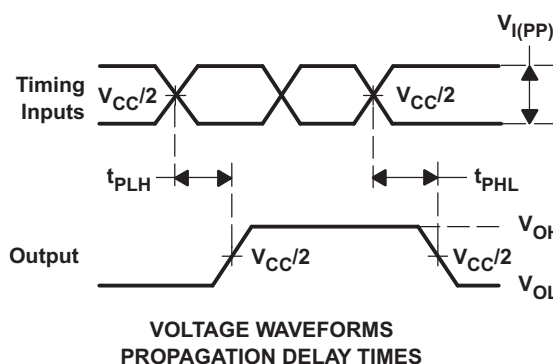
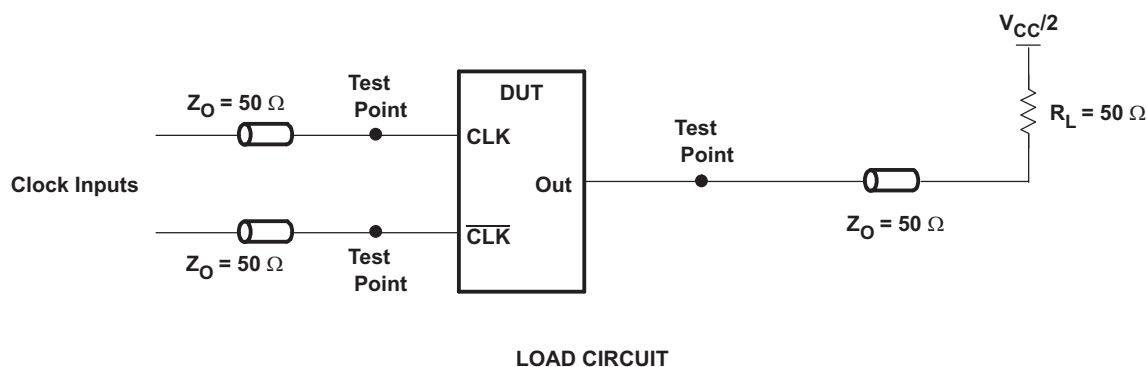


Figure 1. Output Load Circuit for Production Test

Table 1. Propagation Delay (Design Goal as per JEDEC Specification)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 1.8 \text{ V} \pm 0.1 \text{ V}$		UNIT
			MIN	MAX	
$t_{pdm}^{(1)}$	CLK and $\overline{\text{CLK}}$	Q	1.1	1.5	ns
$t_{pdmss}^{(1)}$	CLK and $\overline{\text{CLK}}$	Q		1.6	ns

(1) Includes 350-ps test-load transmission line delay.

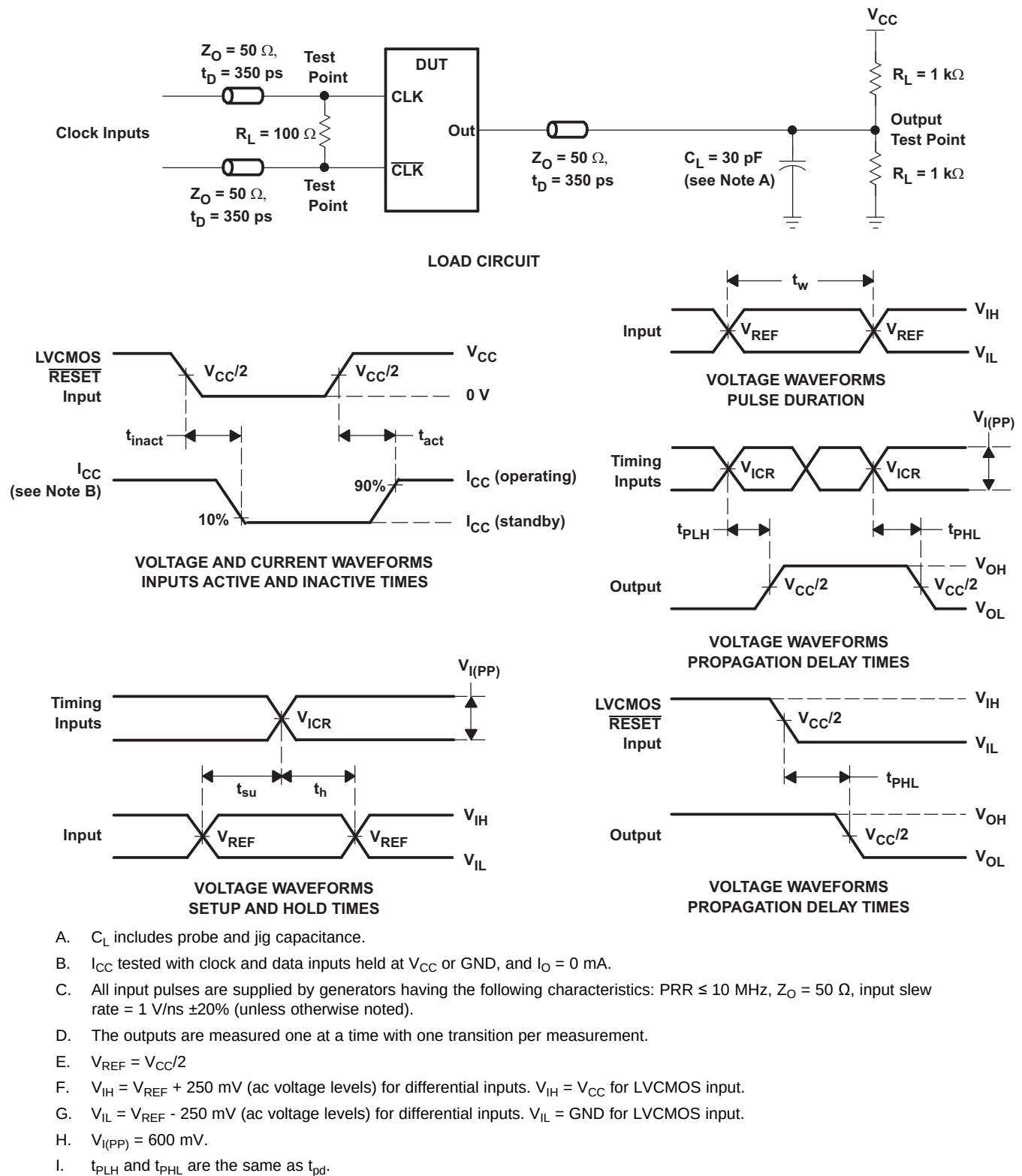
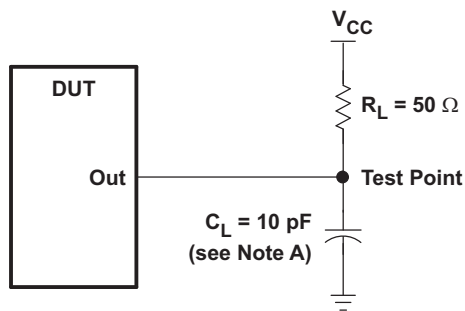
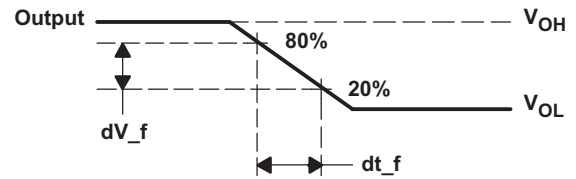


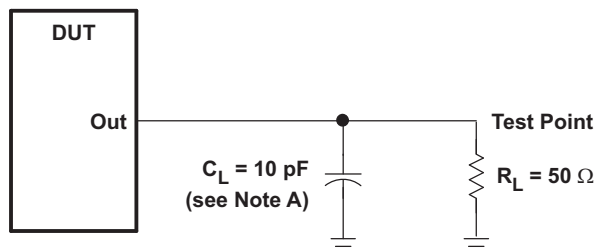
Figure 2. Data Output Load Circuit and Voltage Waveforms



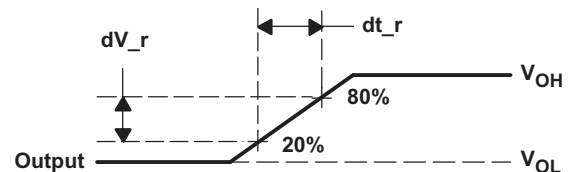
**LOAD CIRCUIT
HIGH-TO-LOW SLEW-RATE MEASUREMENT**



**VOLTAGE WAVEFORMS
HIGH-TO-LOW SLEW-RATE MEASUREMENT**



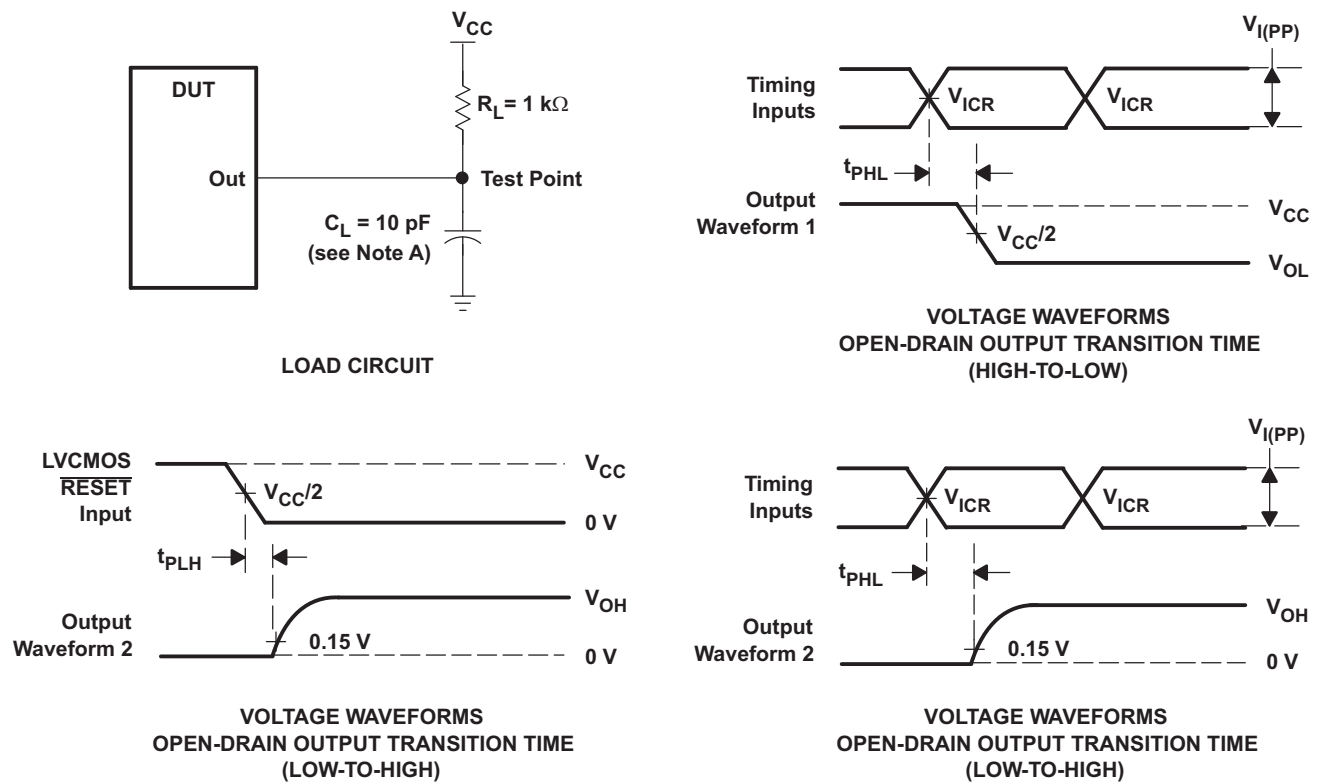
**LOAD CIRCUIT
LOW-TO-HIGH SLEW-RATE MEASUREMENT**



**VOLTAGE WAVEFORMS
LOW-TO-HIGH SLEW-RATE MEASUREMENT**

- A. C_L includes probe and jig capacitance.
- B. All input pulses are supplied by generators having the following characteristics:
 $PRR \leq 10$ MHz, $Z_O = 50 \Omega$, input slew rate = 1 V/ns $\pm 20\%$ (unless otherwise specified).

Figure 3. Data Output Slew-Rate Measurement Information



- C_L includes probe and jig capacitance.
- All input pulses are supplied by generators having the following characteristics:
 $PRR \leq 10\text{ MHz}$, $Z_O = 50\ \Omega$, input slew rate = $1\text{ V/ns} \pm 20\%$ (unless otherwise specified).
- t_{PLH} and t_{PHL} are the same as t_{pd} .

Figure 4. Error Output Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
74SSTUB32868AZRHR	Active	Production	NFBGA (ZRH) 176	1000 LARGE T&R	Yes	SNAGCU	Level-3-260C-168 HR	-40 to 85	SB868A
74SSTUB32868AZRHR.B	Active	Production	NFBGA (ZRH) 176	1000 LARGE T&R	Yes	SNAGCU	Level-3-260C-168 HR	-40 to 85	SB868A

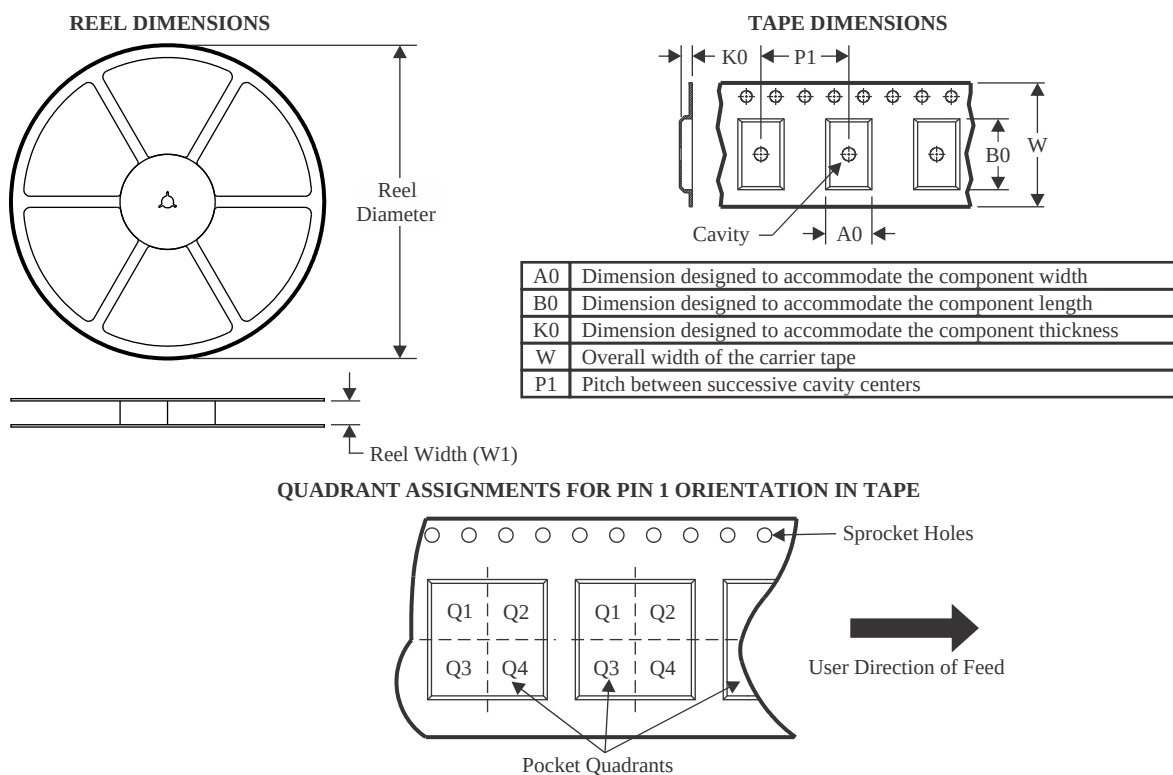
- ⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).
- ⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.
- ⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.
- ⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- ⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- ⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer:The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

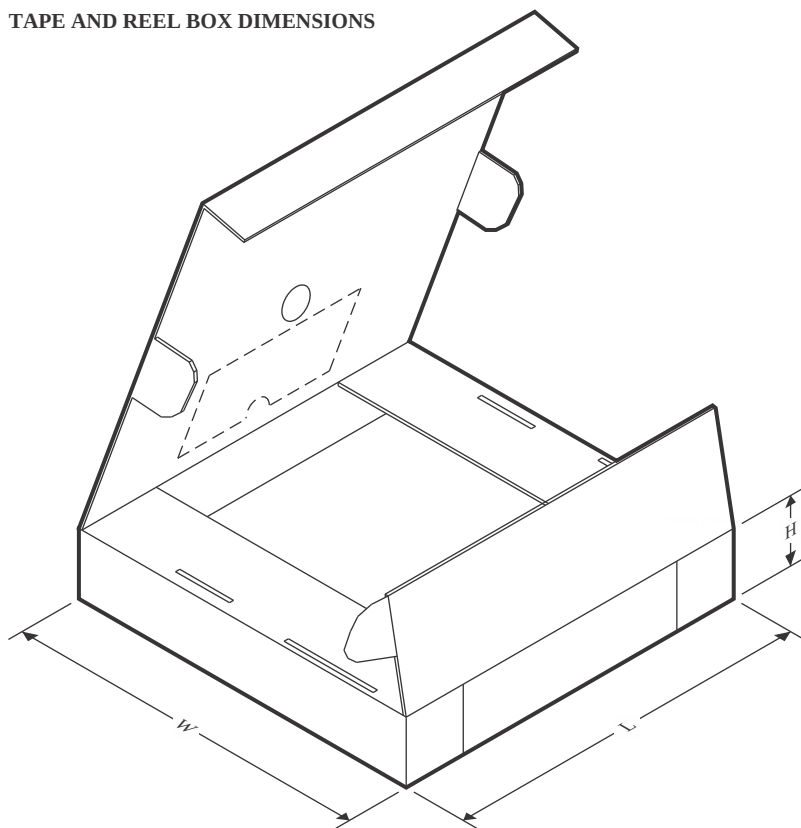
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74SSTUB32868AZRHR	NFBGA	ZRH	176	1000	330.0	24.4	6.3	15.3	1.65	12.0	24.0	Q1

TAPE AND REEL BOX DIMENSIONS

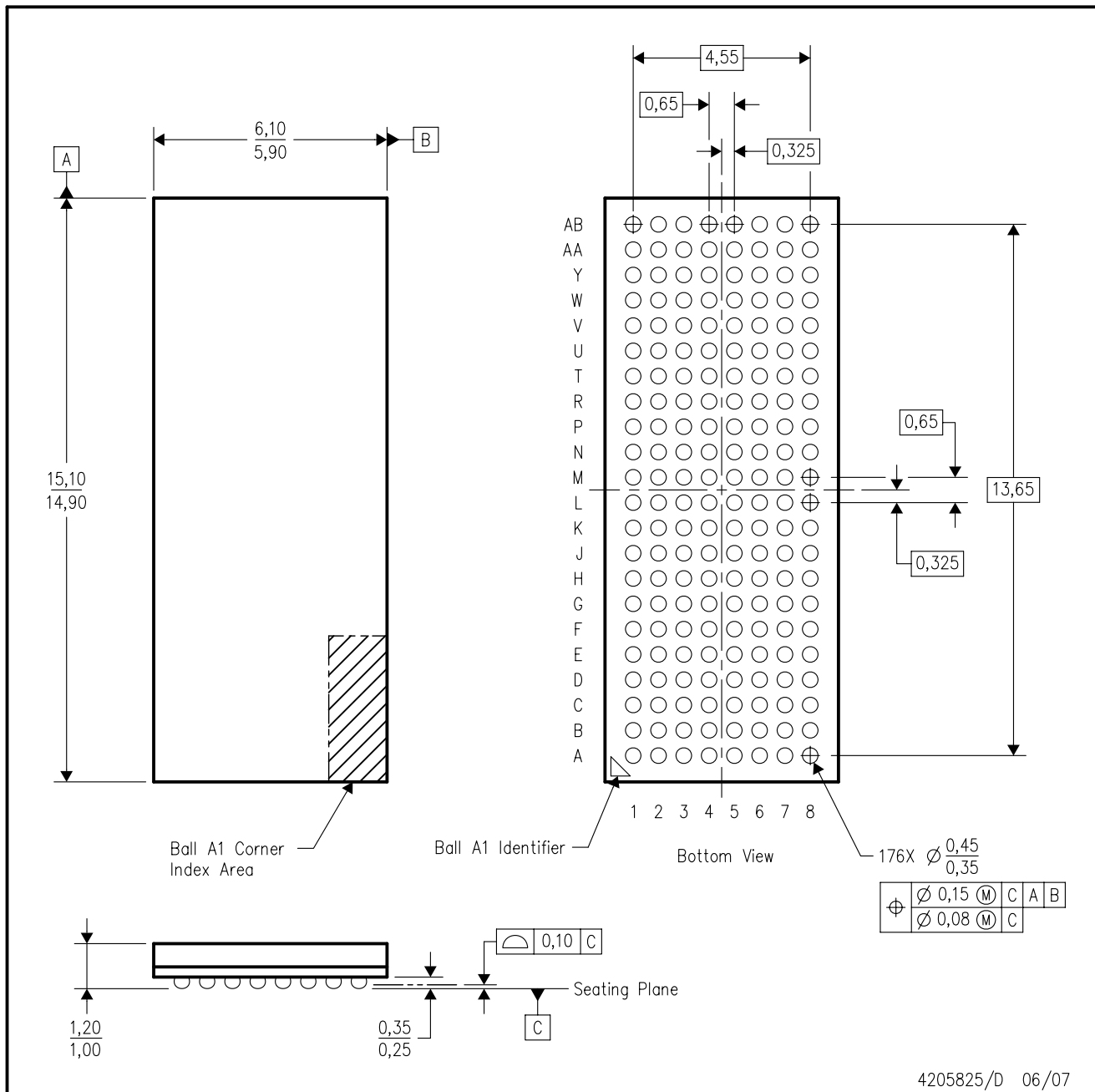


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74SSTUB32868AZRHR	NFBGA	ZRH	176	1000	350.0	350.0	43.0

ZRH (R-PBGA-N176)

PLASTIC BALL GRID ARRAY



- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - Complies to JEDEC MO-246 variation B.
 - This package is lead-free. Refer to the 176 GRH package (drawing 4205824) for tin-lead (SnPb).

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to [TI's Terms of Sale](#) or other applicable terms available either on [ti.com](https://www.ti.com) or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2025, Texas Instruments Incorporated